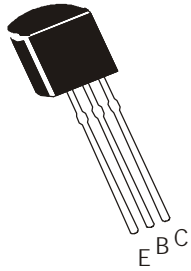


NPN SILICON PLANAR EPITAXIAL TRANSISTORS

CN452 / CN453



TO-92
Plastic Package

General Purpose Transistors designed for Small and Medium Signal Amplification
from D.C to Radio Frequencies

Complementary CP552 and CP553

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	CN452	CN453	UNITS
Collector Base Voltage	V_{CBO}	100	120	V
Collector Emitter Voltage	V_{CEO}	80	100	V
Emitter Base Voltage	V_{EBO}	5.0		V
Peak Pulse Current	I_{CM}	2.0		A
Collector Current Continuous	I_C	1.0		A
Base Current	I_B	200		mA
Power Dissipation @ $T_a=25^\circ\text{C}$	P_D	0.8		W
Power Dissipation @ $T_a=25^\circ\text{C}$	* P_D	1.0		W
Power Dissipation @ $T_c=25^\circ\text{C}$	P_D	2.0		W
Operating and Storage Junction Temperature Range	T_j, T_{stg}	- 65 to +150		$^\circ\text{C}$

*Transistors mounted on printed circuit board. Lead Length 4mm, mounting pad for collector lead min 10mm x 10 mm, copper

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	CN452	CN453	UNITS
Collector Cut Off Current	I_{CBO}	$V_{CB}=80\text{V}, I_E = 0$	<100		nA
		$V_{CB}=100\text{V}, I_E = 0$		<100	nA
Emitter Cut Off Current	I_{EBO}	$V_{EB}=4\text{V}, I_C = 0$	<100	<100	nA
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=150\text{mA}, I_B=15\text{mA}$	<0.7	<0.7	V
Base Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=150\text{mA}, I_B=15\text{mA}$	<1.3	<1.3	V
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$	>80	>100	V
DC Current Gain	* h_{FE}	$V_{CE}=10\text{V}, I_C=150\text{mA}$	40 - 150	40 - 200	
		$V_{CE}=10\text{V}, I_C=1\text{A}$	>10	>10	

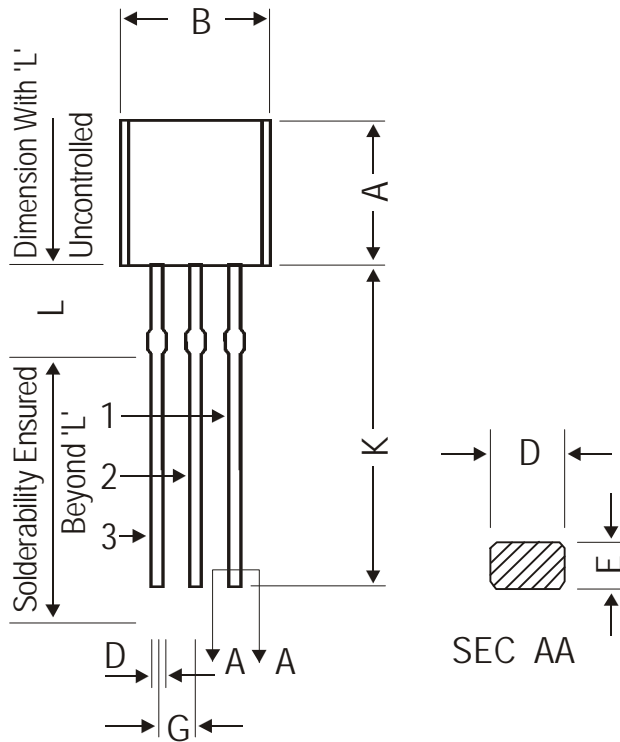
DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	CN452	CN453	UNITS
Transition Frequency	f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=100\text{MHz}$	>100	>100	MHz
Output Capacitance	C_{obo}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$	<15	<15	pF

*Pulse Condition: Pulse Width = 300ms, Duty Cycle $\leq 2\%$.

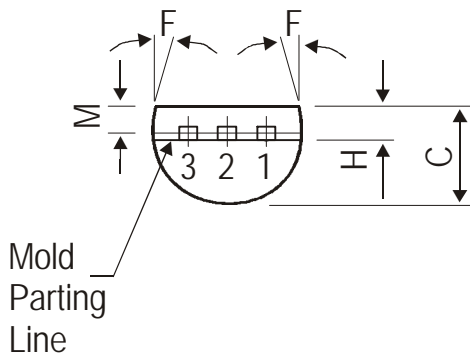
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TO-92 Plastic Package



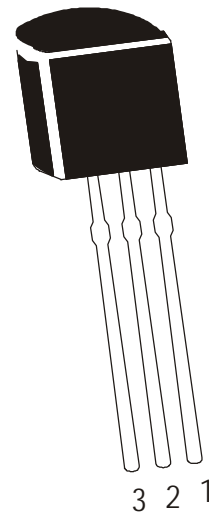
DIM	MIN.	MAX.
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.41	0.55
E	0.35	0.50
F	5 DEG	
G	1.14	1.40
H	1.20	1.40
K	12.70	—
L	1.982	2.082
M	1.03	1.20

All dimensions are in mm



PIN CONFIGURATION

1. COLLECTOR
2. BASE
3. EMITTER



The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

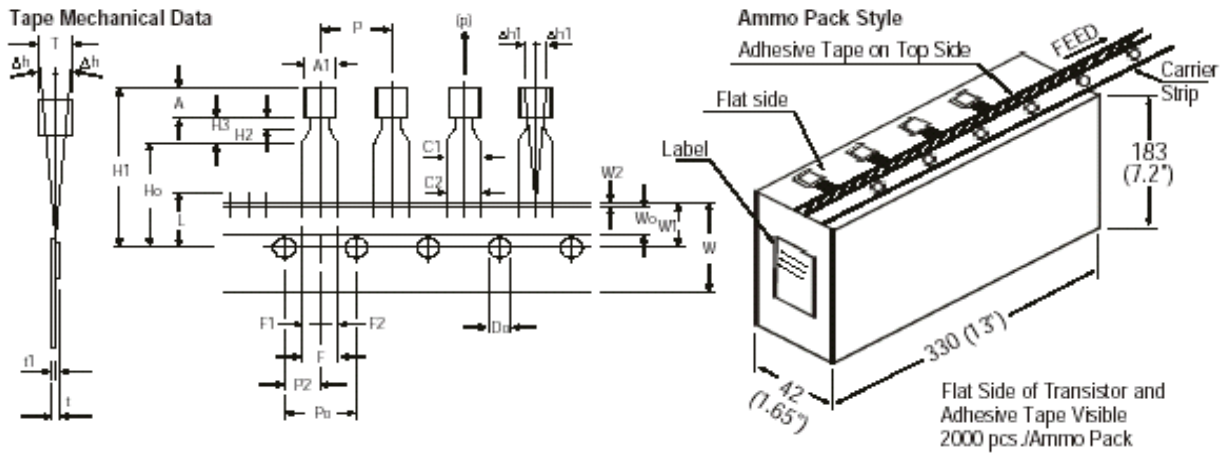
The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

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TO-92 Tape and Ammo Pack



All dimensions are in mm

ITEM	SYMBOL	SPECIFICATION				
		MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.45		5.20		NOTES 1. Maximum alignment deviation between leads will not to be greater than 0.2mm. 2. Maximum non-cumulative variation between tape feed holes shall not exceed 1mm in 20 pitches. 3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive. 4. There will be no more than three (3) consecutive missing components in a tape. 5. A tape trailer, having at least three feed holes are provided after the last component in a tape. 6. Splices should not interfere with the sprocket feed holes.
BODY HEIGHT	A	4.32		5.33		
BODY THICKNESS	T	3.18		4.19		
PITCH OF COMPONENT	P		12.7		± 1.0	
*1 FEED HOLE PITCH	Po		12.7		± 0.3	
*2 FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		± 0.4	
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6 - 0.2	
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		
*4 COMPONENT ALIGNMENT FRONT VIEW	Δh1		0	1.3		
TAPE WIDTH	W		18		± 0.5	
HOLD-DOWN TAPE WIDTH	W0		6		± 0.2	
HOLE POSITION	W1		9		+ 0.7 - 0.5	
HOLD-DOWN TAPE POSITION	W2	0.0		0.7		
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5	
COMPONENT HEIGHT	H1			24.0		
LENGTH OF SNIPPED LEADS	L			11.0		
FEED HOLE DIAMETER	Do		4		± 0.2	
*5 TOTAL TAPE THICKNESS	t			1.2		
LEAD - TO - LEAD DISTANCE	F1, F2	2.40		2.70	- 0.1	
STAND OFF	H2	0.45		1.45		
CLINCH HEIGHT	H3			3.0		
LEAD PARALLELISM	C1 - C2			0.22		
PULL - OUT FORCE	(p)	6N				
					REMARKS *1 Cumulative pitch error 1.0 mm/20 pitch *2 To be measured at bottom of clinch *3 At top of body *4 At top of body *5 t1 0.3 - 0.6 mm	

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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